

Lukas Strizik

List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	Deep red upconversion photoluminescence in Er ³⁺ -doped Yb ₃ Ga ₅ O ₁₂ nanocrystalline garnet. Journal of the American Ceramic Society, 2022, 105, 3391-3402.	3.8	5
2	1.5 $\hat{1}$ /4m photoluminescence and upconversion photoluminescence in GeGaAsS:Er chalcogenide glass. Pure and Applied Chemistry, 2019, 91, 1757-1767.	1.9	4
3	MoSe _x O _y -Coated 1D TiO ₂ Nanotube Layers: Efficient Interface for Light-Driven Applications. Advanced Materials Interfaces, 2018, 5, 1701146.	3.7	16
4	Photoluminescence in pulsed-laser deposited GeGaSbS:Er films. Optical Materials, 2018, 85, 246-253.	3.6	1
5	1.2 \hat{A} and 1.5 \hat{A} near-infrared photoluminescence and visible upconversion photoluminescence in GeGaS:Er ³⁺ /Ho ³⁺ glasses under 980 nm excitation. Journal of Materials Science: Materials in Electronics, 2018, 29, 17314-17322.	2.2	4
6	Physico-chemical and optical properties of Er ³⁺ -doped and Er ³⁺ /Yb ³⁺ -co-doped Ge ₂₅ Ga _{9.5} Sb _{0.5} S ₆₅ chalcogenide glass. Pure and Applied Chemistry, 2017, 89, 429-436.	1.9	7
7	Quadrature frequency resolved spectroscopy of upconversion photoluminescence in GeGaS:Er ³⁺ : I. Determination of energy transfer upconversion parameter. Journal of Materials Science: Materials in Electronics, 2017, 28, 7053-7063.	2.2	8
8	Quadrature frequency resolved spectroscopy of upconversion photoluminescence in GeGaS:Er ³⁺ : II. elucidating excitation mechanisms of red emission besides green emission. Journal of Materials Science: Materials in Electronics, 2017, 28, 7077-7082.	2.2	6
9	Atomic Layer Deposition Al ₂ O ₃ Coatings Significantly Improve Thermal, Chemical, and Mechanical Stability of Anodic TiO ₂ Nanotube Layers. Langmuir, 2017, 33, 3208-3216.	3.5	44
10	In-situ study of athermal reversible photocrystallization in a chalcogenide glass. Journal of Applied Physics, 2017, 122, .	2.5	6
11	Solution-processed Er ³⁺ -doped As ₃ S ₇ chalcogenide films: optical properties and 1.5 $\hat{1}$ /4m photoluminescence activated by thermal treatment. Journal of Materials Chemistry C, 2017, 5, 8489-8497.	5.5	10
12	Penn gap rule in phase-change memory materials: No clear evidence for resonance bonds. APL Materials, 2015, 3, .	5.1	14
13	SnS and SnS ₂ thin films deposited using a spin-coating technique from intramolecularly coordinated organotin sulfides. Applied Organometallic Chemistry, 2015, 29, 176-180.	3.5	14
14	Antireflection In ₂ O ₃ coatings of self-organized TiO ₂ nanotube layers prepared by atomic layer deposition. Physica Status Solidi - Rapid Research Letters, 2015, 9, 516-520.	2.4	13
15	Dynamics of upconversion photoluminescence in Ge ²⁺ Ga ²⁺ S: Er ³⁺ : application of quadrature frequency resolved spectroscopy. Philosophical Magazine Letters, 2015, 95, 466-473.	1.2	8
16	Structural, optical and photoelectrochemical characterizations of monoclinic Ta ₃ N ₅ thin films. Physical Chemistry Chemical Physics, 2015, 17, 23952-23962.	2.8	36
17	Green, red and near-infrared photon up-conversion in Ga ²⁺ Ge ²⁺ Sb ²⁺ S:Er ³⁺ amorphous chalcogenides. Journal of Luminescence, 2014, 147, 209-215.	3.1	17
18	Physico-chemical properties of the thin films of the SbxSe _{100-x} system (x = 90, 85, 80). Thin Solid Films, 2014, 569, 17-21.	1.8	4

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19	Physico-chemical properties of Sb-rich (Sb, In)Te thin films. Journal of Alloys and Compounds, 2014, 617, 306-309.	5.5	4
20	Influence of thermal history on the photostructural changes in glassy As ₁₅ S ₈₅ studied by Raman scattering and <i>ab initio</i> calculations. Journal of Applied Physics, 2013, 114, .	2.5	4
21	Large-area inverse opal structures in a bulk chalcogenide glass by spin-coating and thin-film transfer. Optical Materials, 2013, 36, 390-395.	3.6	10
22	Mixed Organotin(IV) Chalcogenides: From Molecules to SnS ₂ Se Semiconducting Thin Films Deposited by Spin-Coating. Chemistry - A European Journal, 2013, 19, 1877-1881.	3.3	25
23	Up-Conversion in Er ³⁺ -Doped Ge ₂₅ Ga ₅ Sb ₅ S ₆₅ Chalcogenide Glass for Enhancement of Silicon Solar Cell Efficiency. , 2012, , .		0
24	Titanocene(IV) and vanadocene(IV) complexes of dicyanomethanidobenzoate. Journal of Organometallic Chemistry, 2009, 694, 4250-4255.	1.8	7